Docket No.: 60188-127

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Nobuyo SUGIYAMA, et al.

Serial No.:

Group Art Unit:

PATEN

Filed: December 06, 2001

Examiner:

For:

NONVOLATILE SEMICONDUCTOR MEMORY DEVICE AND MANUFACTURING

METHOD THEREOF

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents Washington, DC 20231

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

Serial No.:

Each non-English reference is accompanied by an English Abstract.

Respectfully submitted,

MCDERMOTA, WILL & EMERY

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